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## Cobalt Effect on the Growth of Cadmium Oxide Nanostructure Prepared by Spray Pyrolysis Technique

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#### **Abstract:**

Spray pyrolysis technique (SPT) is employed to synthesize cadmium oxide nanostructure with 3% and 5% Cobalt concentrations. Films are deposited on a glass substrate at 350 °C with 150 nm thickness. The XRD analysis revealed a polycrystalline nature with cubic structure and (111) preferred orientation. Structural parameters represent lattice spacing, crystallite size, lattice parameter and dislocation density. Homogeneous surfaces and regular distribution of atoms were showed by atomic force microscope (AFM) with 1.03 nm average roughness and 1.22 nm root mean square roughness. Optical properties illustrated a high transmittance more than 85% in the range of visible spectrum and decreased with Co concentration increasing. The absorption coefficient values decreased with increasing wavelength and the prepared films had absorption coefficient values greater than 10<sup>4</sup> cm<sup>-1</sup>. The optical energy gap values for allowing direct transition (ADT) varied from 2.78 to 2.63 eV with increasing Co concentration, while the energy gap for allowing indirect transition (AIDT) varied from 1.85 to 1.6 eV with Co concentration.

**Key words:** Cadmium oxide, Cobalt, Optical properties, Spray pyrolysis, Thin films.

#### **Introduction:**

TCOs or transparent conducting oxides are compounds that either have a binary or ternary compound. They are unique materials because they show the transparency of light and electrical conductivity at the same time, therefore, they are a fundamental pillar in the study of the properties of physical substances as well as their adoption in many applications (1). To examine the physical properties of the material, they must be chosen so that they could possess adequate large energy gap to be transparent to visible type of light, which cannot be absorbed, as well as the high concentration of holes and/or electrons, electrical conductivity, that maintain a good mobility (2). Glass fibers are considered transparent material, but are classified as insulators while semiconductors are materials that adopt the doping with metal elements to be able to electrical conductivity. Therefore. transparent conductive oxides embrace the two contradicting properties so that their electrical conductivity can be close to the metals in addition

to the high transparency of light (3,4). TCOs are compound semiconductors made of metal combined with oxygen. This material possesses high optical conductivity within the spectrum region extending from 400 nm to 1500 nm, despite the widening energy gap of these materials, but the conduction band is filled with free electrons due to the high concentration of charge carriers (5,6). Several previous studies dealt with the study of transparent conducting oxides and their physical fundamentals in addition to their structural properties (6–8)

Examples of binary and ternary TCOs are CdO, ZnO, In<sub>2</sub>O<sub>3</sub>, SnO<sub>2</sub>, Ga<sub>2</sub>O<sub>3</sub>, Cd<sub>2</sub>SnO<sub>4</sub>, CdSnO<sub>3</sub>, Zn<sub>2</sub>SnO<sub>4</sub> and CdIn<sub>2</sub>O<sub>4</sub>. Cadmium oxide is one of the most important of these oxides because it has optical energy gap ranging from 2.18 to 2.31 eV at room temperature (2), as well as high transparency of light within the range of the visible spectrum of electromagnetic radiation. It is considered as one of the promising materials in the use of many applications such as solar cells, photodiodes, gas

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and indirect energy gap and finding the limitation of using these films in different optoelectronic applications is the main thrust of this work.

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sensors, light detectors, liquid crystal displays, and other applications that fall into the daily life (9). In literature review, several methods were used to prepare cadmium oxide thin films. In 1987, B. Kavitha et al. (10) developed thin films of CdO on glass substrate at 70°C using the successive ionic layer adsorption and reaction (SILAR). Usharani et al. (7) explored the possibility using cadmium oxide thin films in optical applications using the spray pyrolysis technique and the effect of substrate temperature on the optical and structural properties of these films on a glass substrate in 2015. In 2017, M. R. DAS et al (11) assessed the effect of deposition time on the structural and electrical properties of cadmium oxide thin films on a glass substrate using chemical bath deposition technique (CBD). A. A. Shehab et al. (12) in 2012, studied the effect of tin doping on some physical properties of CdO thin films prepared by thermal vacuum evaporation (PVD) method at 300K with 400 nm thickness. Using reactive magnetron sputtering P. Dhivya et al. (13) prepared thin films of CdO in 2012 at room temperature for sensing the hydrogen gas after annealing the samples at various temperatures. The best results in response to the gas sensor, are given by the sample annealed at 100°C. In 1999, and by using the cadmium chloride solution, M. D. Uplane et al. (14) investigated thin films of CdO using a spray pyrolysis technique with polycrystalline structure. A direct energy gap of 1.9 eV was obtained. Non-transparent CdO films were obtained by J. G. Quinones et al. (15) (2016) using pulsed laser deposition (PLD). Structural analysis showed that the films were crystallized after being heat treated with a temperature of 500°C. Electrical properties indicated an increase in the electrical resistance for thermally annealed samples compared to non-annealed samples.

The purpose of this work is to prepare nanocrystalline thin films of cadmium oxide compound undoped and doped with different concentrations of cobalt using the spray pyrolysis simple and inexpensive technique. Doping effect on the structural, morphological and optical properties such as transmission, absorption coefficient, direct

#### **Materials and Methods:**

tetrahydrate, Cadmium nitrate Cd(NO<sub>3</sub>)<sub>2</sub>.4H<sub>2</sub>O<sub>3</sub> (BDH Chemical England, 99.5% purity), a white powder that is soluble in water used for the preparation of un-doped CdO thin films. The solution was prepared with a concentration of 0.1M according to relation (1). The weight of the material was calculated using a sensitive electronic balance (Mettler HK-160 with 10<sup>-4</sup> g sensitivity). The material was added to 100 ml of distilled water, then gradually dissolved at room temperature using a magnetic stirrer, then left for one hour to make sure there are no residues when spraying the solution on the glass substrate. CdO doped with cobalt thin films were obtained from cobalt chloride (CoCl<sub>2</sub>), (BDH Chemical England, 99.5% purity), a sky blue powder with good solubility in water. The solution was prepared with a concentration of 0.1M, and 3% and 5% of the solution was added to the cadmium nitrate solution, and then mixed well until becoming homogeneous and clear. In that manner, the cadmium nitrate solution with a specific weight ratio of cobalt chloride was obtained.

The films are deposited on glass substrates  $(2.5\times2.5)$  cm<sup>2</sup> after cleaning them thoroughly with water and detergent to ensure that any oil stains or residues of suspended material are removed then washed with distilled water, after that they were immersed in alcohol for 15 minutes in a water bath, then dried by dust cleaner.

where M: Molarity of solution.

 $W_t$ : Dissolved weight of the compound in the size of 1000 ml (g).

 $M_{wt}$ : Molecular weight for the compound cadmium nitrate tetrahydrate (g/mol).

V: Total volume of solution (m<sup>3</sup>).

After several tests, the most appropriate conditions were chosen in the preparation of the films as shown in Table 1.

Table 1. Selected variables for the preparation of thin films

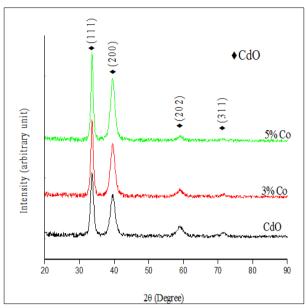
Nozzle- Substrate Distance	Gas Pressure	Spray Time	Stopping Time	Substrate Temperature	Solution Flow Rate	Carrier Gas	Thickness nm	Molarity
15 ±2 cm	1 Bar	5 sec	12 sec	350 °C	2 ml/s	$O_2$	150 ±5	1M

The solution was placed in the container capacity and sprayed on the substrates. The cadmium oxide thin films are obtained through the following chemical reaction:

 $2CdO(NO_3)_2 \xrightarrow{heat} 2CdO + 4NO_2 \uparrow + O_2 \uparrow \dots \dots 2$ After the deposition process, the best-prepared films were selected in terms of their homogeneity and adhesion strength to the substrate so that they cannot be cleared by hand and are free from discolored spots, impurities, and cracks in the films. The homogeneity of the films is diagnosed in stages, first with the eye. If none of the above defects are detected using an optical microscope, the crystal structure is examined using a diffraction method with x-rays system (Cu-K $\alpha$ ,  $\lambda$ =0.154 nm, 40 kV, 20 mA. Measurements of the optical properties were performed by using UV-VIS double beam Spectrometer with the range of 200-900 nm.

#### Structural Analysis XRD characterization

Figure 1 shows the results of XRD analysis for undoped CdO and doped with different concentrations of Co thin films. The figure revealed a polycrystalline nature with cubic structure with diffraction peaks returning to the crystalline plane (111) (200) (202) (311) at 20 of 26.4°, 32.4°, 52.1° and 64.3°, respectively. This result agrees with articles in (2,10,16). That corresponds well with standard card of data (JCPDS Card No. 96-900-6693) (17). These peaks show a variation in their intensity with a strong, sharp peak toward a plane (111), that is a property possessed by high crystallization material and it is representing the preference for crystalline development, agrees with the results obtained by (16,18). The reason for the preference for film growth at the (111) peak is that the energy of the surface density of this orientation is lower than other crystalline orientations (19). However, by increasing Co concentration, the CdO (111) orintation becomes more prominent. There was an increasing in CdO (111) orintation intensity which indicates an improving crystallinity and increasing the crystallite size (D) as increasing Co concentration. A matching of the calculated dhkl values and the standard ones confirms that the Co doped CdO films at 3% and 5% are also crystallized in the cubic structure.



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Figure 1. XDR diagram for un-doped and Co doped CdO.

Table 2 shows a decrease in  $\beta$ , which resulted in a rise in the intensity of dominant peaks, consistent with the Ref. (11,20) indicating the improvement in the crystalline growth of the deposited atoms accompanied by an increase in crystallite size with increasing of Co doping concentration, a similar result obtained by the researcher (21). The CdO:Co nanostructure at 5% exhibited a larger crystallite size, it found about 11.1 nm, while it was 8.4 nm and and 9.9 nm for undoped and 3% Co-doped respectively, as shown in Table 2. In addition, it was evident that there is a decrease in the values of dislocations with increasing Cobalt concentration. This may be due to the fact that increasing of Co concentration reduce the crystalline defects accompanying the process of crystalline growth.

There was no change in the location of the diffraction peaks at 3% dopant ratio, which indicates stability in the crystalline structure of the prepared films before and after doping at this ratio. Maybe due to the fact that the 3% doping ratio was a diminutive, so does not lead to deforming the crystalline structure. When the dopant ratio reached 5%, there was a small shift in the diffraction peaks towards the low  $2\theta$  and thus an increase in the lattice parameter (a) same behavior for CdO when doped with fluorine (21), with an increase in particle size and a decrease in ( $\beta$ ).

Table 2. structural parameters of thin films.

Co- Concentration %	2θ (Deg.)	FWHM (Deg.)	d <sub>hkl</sub> Exp.(Å)	d <sub>hkl</sub> Std.(Å)	G.S (nm)	hkl	a (Å)	$\delta \times 10^{12}$ lines/m <sup>2</sup>	Phase
Pure	33.6354	0.9938	2.6624	2.6683	8.4	111	4.61138	1.40	CdO
	39.5981	1.5901	2.2741	2.3108	5.3	200	3.93892	3.50	CdO
	58.9770	2.1863	1.5649	1.634	4.2	202	2.71042	5.70	CdO
	71.4988	1.6894	1.3185	1.3935	5.8	311	2.28364	3.00	CdO
3%	33.6354	0.8400	2.6624	2.6683	9.9	111	4.61138	1.00	CdO
	39.5981	1.5444	2.2741	2.3108	5.5	200	3.93892	3.30	CdO
	58.9770	1.9502	1.5649	1.634	4.7	202	2.71042	4.60	CdO
	71.4988	1.5700	1.3185	1.3935	6.2	311	2.28364	2.60	CdO
5%	33.6304	0.7490	2.6628	2.6683	11.1	111	4.61204	0.81	CdO
	39.5931	1.4664	2.2744	2.3108	5.8	200	3.93939	3.00	CdO
	58.9720	1.7442	1.5650	1.634	5.2	202	2.71062	3.60	CdO
	71.4938	1.4720	1.3185	1.3935	6.7	311	2.28378	2.30	CdO

#### **Atomic Force Microscopy (AFM):**

Surface distribution of atoms on glass substrates was studied using an atomic force microscope for un-doped CdO and doped with 3 and 5% Co. Figure 2 shows the density of grain distribution and three-dimensional images. It reveals a homogeneous distribution of the clusters, noting that the process of growth of atoms was regular and the deposition process was successful. The parameters of the AFM have been listed in Table 3. A study of surface characteristics showed that the particle size of the films under study increased by increasing the Co-concentration, which is consistent with the results of the study of X-ray diffraction. In addition, there was an increase in the

roughness of the surface with increasing dopant concentration, may be attributed to the increase in particle size with increasing Co-doping (22).

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Table 3. Variation of average diameter and roughness as a function to the dopant concentration

Type	Average	Average	r.m.s	
	diameter	roughness	roughness	
	(nm))	(nm)	(nm)	
Pure	22	1.03	1.22	
3% Co	28	1.44	1.65	
5% Co	40	2.59	3	

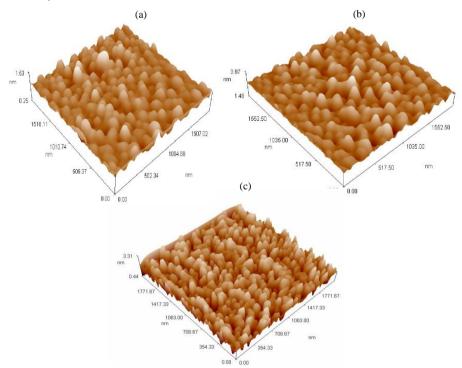


Figure 2. AFM images for; (a) un-doped CdO, (b) doped with 3% Co, and (c) doped with 5% Co thin films.

#### Optical Properties: Transmittance (T%):

Figure 3 shows transmittance spectrum of prepared films within the range 300-1100 nm of wavelength, undoped samples reported higher values of transmittance in UV-visible range towards IR of the electromagnetic spectrum, higher than 85%, agrees with ref. (23), therefore these films can be used in the field of optical windows applications. The films showed similar behavior for all optical analysis, which gives an impression of their stability. However, after doping with different concentrations of cobalt, there was an inversely related between T% and doping concentration. Undoped film has 78.25% of transmittance as the average value while decreased to 74.83% and 69.93% for 3% and 5% Co-doped respectively. This decrease in T% after the doping can be attributed to the increase in crystallite size, as shown in XRD analysis, which refers to an absorbance increase in (A) vs. doping

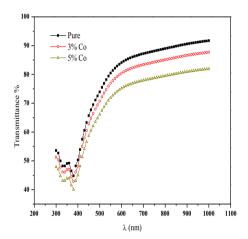


Figure 3. Transmittance as a function to the wavelength of un-doped CdO and doped with different concentrations of Co.

#### **Absorption Coefficient (α):**

Figure 5 shows the absorption coefficient curve, which reveals increasing in its values with a decrease in wavelength. As mentioned in the discussion section of optical transmittance, there was a decrease in absorbance towards increasing wavelength leads to a decrease in absorption coefficient ( $\alpha$ ) because of both absorbance and the absorption coefficient linked by low of lambert, the relation 4:(25)

$$\alpha = 2.303 \frac{A}{t} \dots \dots \dots 4$$

#### t: Film thickness.

While there was an increase in  $\alpha$  accompanied by a drag out in the absorption edge towards higher  $\lambda$  with increasing of Co-dopant concentration, as shown in Table 5, which gives us an indication of a decrease in energy gap values, as will be discussed

concentration. Table 4 shows the transmittance at the absorption edges ( $T_{edge}$ ), at the middle of spectrum ( $T_{middle}$ ), the maximum transmittance ( $T_{maximum}$ ), and the average transmittance ( $T_{average}$ ). As well as the optical measurements revealed decreasing in absorbance vs wavelength, as shown in Fig.4, within the measured wavelength range according to the relation 3:(24)

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$$T = e^{-2.303 A} \dots \dots 3$$

T: transmittance and A: absorbance.

Table 4. The Transmittance at the absorption edges, middle of spectrum, the maximum transmittance, and the average transmittance.

Cobalt concentration %	$\begin{array}{c} T_{\rm edge} \\ \% \end{array}$	$T_{\substack{\text{middle}\\ \%}}$	$T_{\substack{\text{maximum}\\ \%}}$	$T_{average} \ \%$
0	44.80	80.49	91.72	78.25
3	42.84	76.97	87.71	74.83
5	40.04	71.93	81.97	69.93

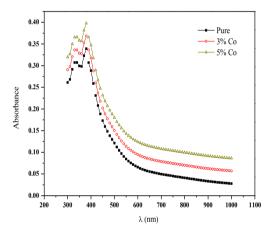


Figure 4. Absorbance as a function to the wavelength of un-doped CdO and doped with different concentrations of Co.

later. This may be due to the doping that resulted in the generation of donor energy levels within the energy gap near the conduction band, which in turn led to the absorption of low-energy photons and thus a clear increase in absorption factor values (26). Figure 5 shows also higher values for  $\alpha$  rather than  $10^4$ , this may be indicative of direct electronic transitions between the valence and conduction bands, which may be attributed to an increase in the absorption values within this region.

Table 5. The absorption coefficient at the absorption edges ( $\alpha_{edge}$ ), middle of spectrum ( $\alpha_{middle}$ ), the maximum absorption coefficient ( $\alpha_{maximum}$ ), and the average value ( $\alpha_{average}$ ).

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	Cobalt concentration	α <sub>edge</sub> (cm <sup>-</sup>	$\alpha_{\text{middle}}$ $(\text{cm}^{-})$	α <sub>maximum</sub> (cm <sup>-</sup>	α <sub>average</sub> (cm <sup>-</sup>
	%	$^{1}\times10^{4}$ )	$^{1}\times10^{4}$ )	$^{1}\times10^{4}$ )	$^{1}\times10^{4}$ )
	0	3.90	0.97	0.32	1.23
	3	4.24	1.31	0.66	1.56
	5	4.58	1.65	0.99	1.90

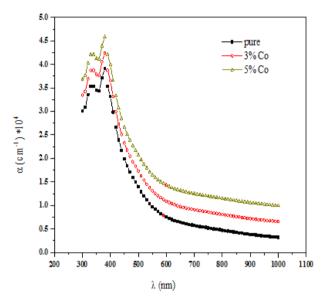


Figure 5. Absorption coefficient vs wavelength for CdO and Co:CdO thin films.

### Energy Gap $(E_g)$ :

The optical energy gap values for direct electronic transition of both types allowed and unallowed are calculated through the relation 5: (27)

A: constant depends on the structure of material and if the electronic transition from the allowed direct type, then (n) will be taking the value  $(\frac{1}{2})$ , while (n) will be taking the value (2) for the allowed indirect transition (28). Figure 6a shows the optical energy gap values for allowed direct transition (ADT) which have the values 2.78, 2.7 and 2.63 eV for un-doped CdO and doped with 3% and 5% Co thin films respectively. The results agreeing with reported literature (2,16,29). These values are confirming the formation of nanostructures thin films (30). Also means that the absorption of photons was direct, but the breadth of absorption region indicates that there were different types of absorption, indirect or by the tails of localized levels inside the energy gap that arose from the change in the crystal structure obtained by adding Co to the alloy. The absorption edge shifted from 380 nm toward the infrared as Co content increased.

At 3%, the absorption edge appeared at 389 nm, while at 5% the absorption edge was at 392 nm. The change in the energy gap can be the reason for the increase in particle size with the increase in the doping concentration (31). Figure 6b shows the change in values of the energy gap and particle size as a function of doping concentration depending on the values listed in Table 6. The graph in Fig.6c shows the plot of  $(\alpha h v)^{\frac{1}{2}}$  vs photon energy for the allowed indirect transition (AIDT), which has the values 1.85, 1.7 and 1.55 eV for pristine CdO, 3% Co doped, and 5% Co doped, respectively.

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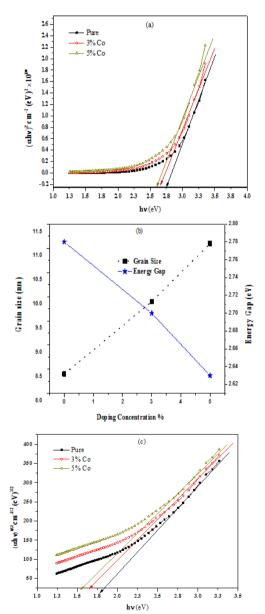


Figure 6. a- Energy gap with photon energy for the allowed direct transition, b- Particle size and  $E_{\rm g}$  vs doping concentration, c- Energy gap with photon energy for the allowed indirect transition.

Table 6. Relation between grain size and optical energy gap according to Co-dopant variation.

Type	G.S (nm)	$E_{\rm g}$ (ADT)eV	E <sub>g</sub> (AIDT)eV
Pure	8.4	2.78	1.85
3% Co	9.9	2.7	1.7
5% Co	11.1	2.63	1.55

#### **Conclusions:**

Undoped and Cobalt doped CdO thin films are successfully synthesized by (SPT) on glass substrate. Co doping of CdO leads to increasing surface roughness and energy bandgap. The increase in bandgap could lead to a decrease in electrical conductivity. Therefore, Co doping is not recommended in transparent conductive oxides applications but it can work as a window in some other applications. The increase in grain size diameter can approve that Co is encouraging certain orientations growth and introducing thin films with better quality. Finally, the surface roughness increases with increased cobalt ratios, and this contributes greatly to the advantage of using these ratios in gas sensor devices.

#### **Authors' declaration:**

- Conflicts of Interest: None.
- We hereby confirm that all the Figures and Tables in the manuscript are mine ours. Besides, the Figures and images, which are not mine ours, have been given the permission for republication attached with the manuscript.
- Ethical Clearance: The project was approved by the local ethical committee in University of Anbar.

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# تأثير الكوبالت على نمو التركيب النانوي من أوكسيد الكادميوم المحضر بتقنية التحلل الكيميائي الحراري جمال مال الله رزيج 1 عثمان سالم ابراهيم 2 ممال مال الله رزيج 1

القسم الفيزياء، كلية العلوم، جامعة الانبار، الرمادي، العراق وزارة التربية العراقية، الانبار، العراق قسم الكيمياء، كلية العلوم، جامعة النهرين، بغداد، العراق

#### لخلاصة.

تم استخدام تقنية الرش الكيميائي الحراري (SPT) للحصول على تركيب نانوي من اغشية اوكسيد الكادميوم المشوبة بالكوبالت بنسبة 3% و5%. تم ترسيب الأفلام على قواعد من الزجاج بدرجة حرارة 350 درجة مئوية وبسمك 150 نانومتر. أظهرت نتائج حيود الاشعة السينية (XRD) بنية بلورية متعددة التبلور ذات تركيب مكعبي بأفضلية إنماء بلوري باتجاه المستوي (111). اشتملت فحوصات الاشعة السينية أيضا دراسة المسافة البينية بين المستويات البلورية والحجم البلوري وثوابت الشبيكة وكثافة الانخلاعات البلورية. سطوح متجانسة وتوزيع منتظم للذرات اظهرتها صور مجهر القوى الذرية (AFM) بمعدل خشونة للسطح بمقدار 1.2 نانومتر ومتوسط جذر تربيعي للخشونة بمقدار 1.2 نانومتر. كشفت دراسة الخواص البصرية أن الأفلام المحضرة تمتلك نفاذية بصرية أكبر من 85% في مدى الطيف المرئي وتقل قيمتها مع زيادة الطول الموجي وأن الاغشية المحضرة تمتلك قيم معامل المتصاص مع زيادة الطول الموجي وأن الاغشية المحضرة تمتلك قيم معامل المتصاص أكبر من 1.85 إلى 2.73 الكترون فولت مع زيادة المصاص أكبر من 1.85 الكترون فولت مع زيادة تركيز الكوبالت، في حين تراوحت قيم فجوة الطاقة للانتقال غير المباشر المسموح من 1.85 إلى 2.63 الكترون فولت.

الكلمات المفتاحية: أو كسيد الكادميوم، كو بالت، الخصائص البصرية، الرش الكيميائي، أغشية رقيقة.